

IPW

**IN THE UNITED STATES PATENT AND TRADEMARK OFFICE**

In re Application of

Hideto HIDAKA

Application No.: 10/615,379

Filed: July 09, 2003



Customer Number: 20277

Confirmation Number: CNF NO. 1384

Group Art Unit: 2824

Examiner: Nguyen, Van Thu T

For: THIN FILM MAGNETIC MEMORY DEVICE HAVING A HIGHLY INTEGRATED MEMORY ARRAY

**INFORMATION DISCLOSURE STATEMENT**

Mail Stop ISSUE FEE  
Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

Dear Sir:

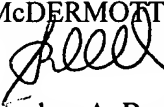
This Information Disclosure Statement is being filed under Rule 37 CFR 1.97(i), wherein applicants are submitting references before the grant of a patent to be placed in the file.

Accordingly, copies of the references as listed on the attached Form PTO-1449 are submitted herewith for placement in the file. No certification or fees are deemed necessary.

Please charge any shortage in fees due in connection with the filing of this paper, including extension of time fees, to Deposit Account 500417 and please credit any excess fees to such deposit account.

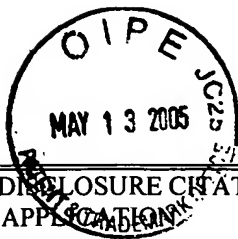
Respectfully submitted,

McDERMOTT WILL & EMERY LLP

  
Stephen A. Becker  
Registration No. 26,527

**Please recognize our Customer No. 20277 as our correspondence address.**

600 13<sup>th</sup> Street, N.W.  
Washington, DC 20005-3096  
Phone: 202.756.8000 SAB:tlg  
Facsimile: 202.756.8087  
Date: May 13, 2005



SHEET 1 OF 1

INFORMATION DISCLOSURE CITATION IN AN APPLICATION (PTO-1449)				ATTY. DOCKET NO. <b>057454-0964</b>		SERIAL NO. <b>10/615,379</b>	
				APPLICANT <b>Hideto HIDAKA</b>			
				FILING DATE <b>July 09, 2003</b>		GROUP <b>2824</b>	
U.S. PATENT DOCUMENTS							
EXAMINER'S INITIALS	CITE NO.	Document Number Number-Kind Code2 (if known)		Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear	
		US	6,055,178	4/25/2000	Naji		
		US	5,276,650	1/4/1994	Kubota		
		US	5,619,447	4/8/1997	Tai		
		US					
FOREIGN PATENT DOCUMENTS							
EXAMINER'S INITIALS	CITE NO.	Foreign Patent Document Country Code3 – Number 4 –Kind Code5 (if known)		Publication Date MM-DD- YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines Where Relevant Figures Appear	Translation Yes      No
OTHER ART (Including Author, Title, Date, Pertinent Pages, Etc.)							
EXAMINER'S INITIALS	CITE NO.	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.					
		SCHEUERLEIN, Roy E. et al., "Shared Word Line DRAM Cell", IEEE Journal of Solid-State Circuits, Vol. 19, No. 5, October 1984, pp. 640-645					
		TEHRANI, S. et. al., "Recent Developments in Magnetic Tunnel Junction MRAM", IEEE Transactions on Magnetism, Vol. 36, No. 5, September 2000, pp. 2752-2757					
EXAMINER				DATE CONSIDERED			

\*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.  
1 Applicant's unique citation designation number (optional). 2 Applicant is to place a check mark here if English language Translation is attached.